Registration No :					

Total Number of Pages: 02

M.Tech P2MDCC10

2nd Semester Regular / Back Examination 2018-19 EXPERIMENTAL STRESS ANALYSIS BRANCH: MACHINE DESIGN, MECH. SYSTEM DESIGN

Max Marks : 100 Time : 3 Hours Q.CODE : F432

Answer Question No.1 (Part-1) which is compulsory, any eight from Part-II and any two from Part-III.

The figures in the right hand margin indicate marks.

Part_ I

Q1 Only Short Answer Type Questions (Answer All-10)

(2 x 10)

- a) What are the material used for resistance typ strain gauges?
- b) Define strain sensitivity and gage factor?
- c) State and difference between plane stress and plane strain problem.
- d) State advantages of metal foil strain gage over bonded wire strain gage.
- e) Explain the stress optic law.
- f) Name the differentr material used in brittle boating method.
- **g)** State two method of separation of principal stresses in two dimensional photoelasticity.
- h) Explain refference array in Moire fringe technique.
- i) What is the method of compensation in photo elasticity analysis method?
- i) What are isocline and isochromatics?

Part-II

Q2 Only Focused-Short Answer Type Questions- (Answer Any Eight out of Twelve) (6 x 8)

- a) Explain potentiometer circuit for strain measurement.
- b) What are strain rosette? Give the configuration of star and delta strain rosette.
- c) What is meant by null balance and why it is needed at the beginning of the experiment?
- **d)** Explain the use of monochromatic and white light in photoelastic experiment.
- e) Discuss the advantages and limitations of brittle coating method.
- f) Explain the use of plane polariscope.
- **g)** Explain the circular polariscope?
- **h)** State parameters for consideration for a good photoelastic material.
- i) What is reflection polariscope? Explain
- j) Explain the Frozen stress method of 3D photoelasticity
- k) Expalin the use of semiconductor strain gauges
- I) Explain the Grid method of strain analysis.

Part-III

Only Long Answer Type Questions (Answer Any Two out of Four)

- Readings of a strain rosette are : ϵ_0 = 600 x 10⁻⁶ , ϵ_{45} = -150 x 10⁻⁶ , ϵ_{120} = 250 x 10⁻⁶. (16) Find the magnitude and direction of principal strains. Also find the principal stresses. (Take E= 205 GPa and v=0.3).
- Explain the WSB circuit used for strain measurement, and derive the expression for the gage factor and gage sensitivity. Also explain the provission of temperature comensation in the same circuit.
- Discuss the geometric approach of Moire fringe strain anlysis. Describe the approach to measure normal strain and shear strain using the Moire-fringe effect. (16)
- Q6 Explain the brittle coating method for strain and stress analysis. Also explain the callibration method. (16)